## NSN 5961-00-267-5418

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View Online at https://aerobasegroup.com/nsn/5961-00-267-5418 **Inclosure Material:** Metal **Overall Length:** 0.388 inches **Overall Height:** 0.385 inches **Overall Diameter:** 0.690 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 1.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 5.00 amperes all primaries **Power Rating Per Characteristic:** 80.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 wire hook and 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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